SWITCHMODE™ Schottky Power Rectifier

DPAK Power Surface Mount Package

... employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State of the art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies, free wheeling diode and polarity protection diodes.

- Highly Stable Oxide Passivated Junction
- Guardring for Stress Protection
- Matched Dual Die Construction May be Paralleled for High Current Output
- High dv/dt Capability
- Short Heat Sink Tap Manufactured Not Sheared
- Very Low Forward Voltage Drop
- Epoxy Meets UL94, VO at 1/8"

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 0.4 gram (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 75 units per plastic tube
- Available in 16 mm Tape and Reel, 2500 units per Reel, Add "T4" to Suffix part #
- Marking: B1035CL

MAXIMUM RATINGS

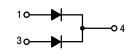
Please See the Table on the Following Page



ON Semiconductor[™]

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 10 AMPERES 35 VOLTS





CASE 369A PLASTIC

MARKING DIAGRAM



B1035CL = Device Code

ORDERING INFORMATION

Device	Package	e Shipping	
MBRD1035CTL	DPAK	75 Units/Rail	
MBRD1035CTLT4	DPAK	2500/Tape & Reel	

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	35	Volts
Average Rectified Forward Current (At Rated V _R , $T_C = 115^{\circ}C$)	Per Leg Per Package	lo	5.0 10	Amps
Peak Repetitive Forward Current (At Rated V _R , Square Wave, 20 kHz, T _C = 115°C)	Per Leg	I _{FRM}	10	Amps
Non–Repetitive Peak Surge Current Per Package (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)		I _{FSM}	50	Amps
Storage / Operating Case Temperature		T _{stg,} T _c	-55 to +125	°C
Operating Junction Temperature		ТJ	-55 to +125	°C
Voltage Rate of Change (Rated V _R , T _J = 25°C)		dv/dt	10,000	V/µs
HERMAL CHARACTERISTICS		LL		
Thermal Resistance – Junction to Case	Per Leg	$R_{\theta JC}$	2.43	°C/W
Thermal Resistance – Junction to Ambient (Note 1.)	Per Leg	R _{θJA}	68	°C/W
LECTRICAL CHARACTERISTICS				
Maximum Instantaneous Forward Voltage (Note 2.) see Figure 2 $I_F = 5 \text{ Amps}, T_J = 25^{\circ}\text{C}$ $I_F = 5 \text{ Amps}, T_J = 100^{\circ}\text{C}$ $I_F = 10 \text{ Amps}, T_J = 25^{\circ}\text{C}$ $I_F = 10 \text{ Amps}, T_J = 100^{\circ}\text{C}$	Per Leg	VF	0.47 0.41 0.56 0.55	Volts
Maximum Instantaneous Reverse Current (Note 2.) see Figure 4 $(V_R = 35 V, T_J = 25^{\circ}C)$ $(V_R = 35 V, T_J = 100^{\circ}C)$ $(V_R = 17.5 V, T_J = 25^{\circ}C)$	Per Leg	I _R	2.0 30 0.20	mA

5.0

 $(V_R = 17.5 \text{ V}, \text{ } \text{T}_\text{J} = 25^\circ\text{C}) \\ (V_R = 17.5 \text{ V}, \text{ } \text{T}_\text{J} = 100^\circ\text{C})$

1. Rating applies when using minimum pad size, FR4 PC Board 2. Pulse Test: Pulse Width \leq 250 µs, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

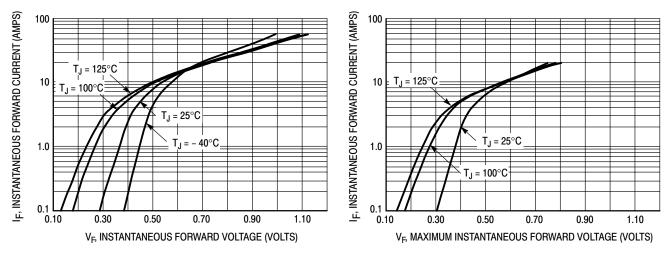


Figure 1. Typical Forward Voltage Per Leg



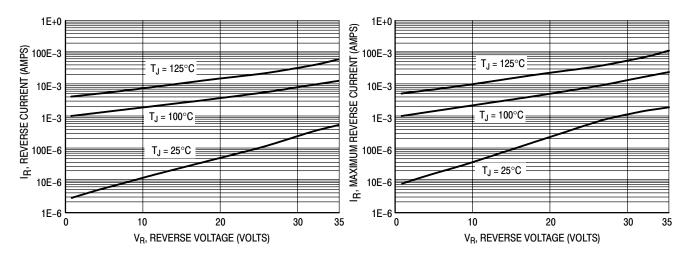
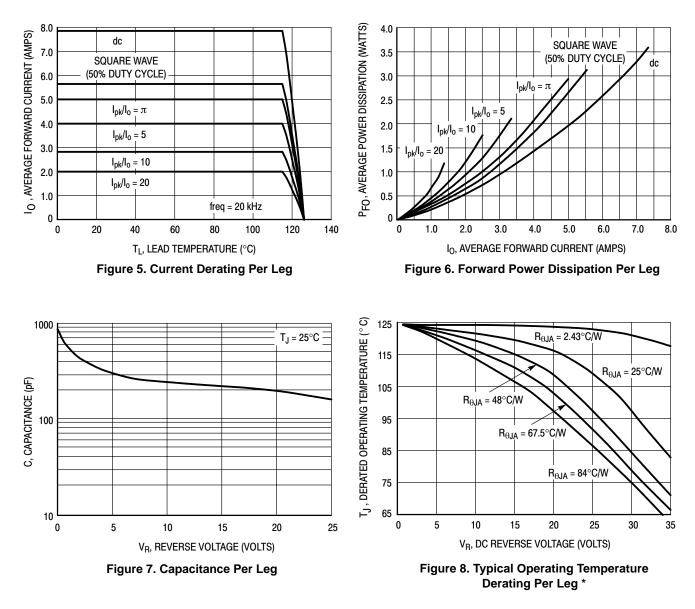


Figure 3. Typical Reverse Current Per Leg

Figure 4. Maximum Reverse Current Per Leg



* Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of T_J therefore must include forward and reverse power effects. The allowable operating T_J may be calculated from the equation: $T_J = T_{Jmax} - r(t)(Pf + Pr)$ where

r(t) = thermal impedance under given conditions,

Pf = forward power dissipation, and

Pr = reverse power dissipation

This graph displays the derated allowable T_J due to reverse bias under DC conditions only and is calculated as $T_J = T_{Jmax} - r(t)Pr$, where r(t) = R thia. For other power applications further calculations must be performed.

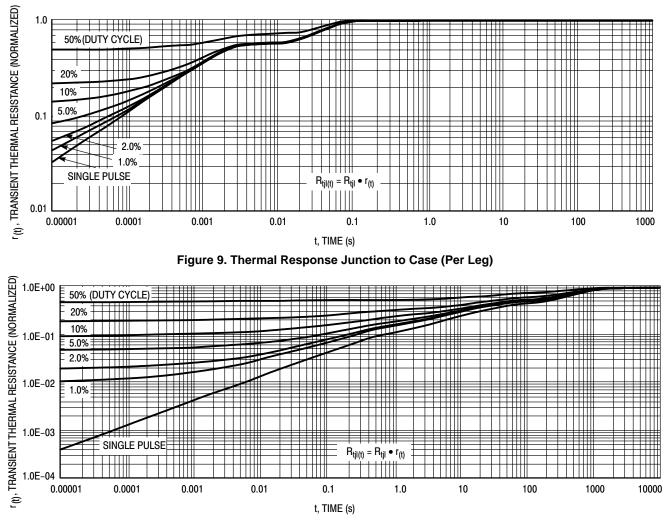
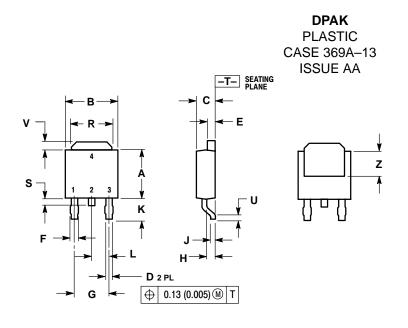


Figure 10. Thermal Response Junction to Ambient (Per Leg)

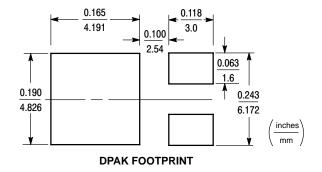
PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.250	5.97	6.35	
в	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.033	0.040	0.84	1.01	
н	0.037	0.047	0.94	1.19	
G	0.180 BSC		4.58 BSC		
Н	0.034	0.040	0.87	1.01	
L	0.018	0.023	0.46	0.58	
Κ	0.102	0.114	2.60	2.89	
Г	0.090 BSC		2.29 BSC		
R	0.175	0.215	4.45	5.46	
s	0.020	0.050	0.51	1.27	
U	0.020		0.51		
۷	0.030	0.050	0.77	1.27	
Ζ	0.138		3.51		

STYLE 3: PIN 1. ANODE 2. CATHODE 3. ANODE 4. CATHODE



<u>Notes</u>

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